

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE

2SC5376

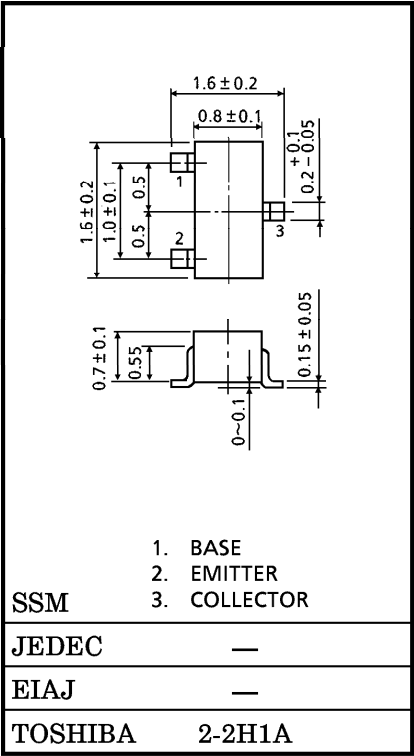
AUDIO FREQUENCY GENERAL PURPOSE AMPLIFIER APPLICATIONS
FOR MUTING AND SWITCHING APPLICATIONS

Unit in mm

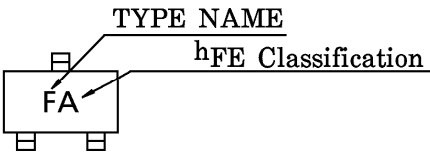
- Low Collector Saturation Voltage : $V_{CE(sat)}(1) = 15mV$ (Typ.)
@ $I_C = 10mA / I_B = 0.5mA$
- High Collector Current : $I_C = 400mA$ (Max.)

MAXIMUM RATINGS (Ta = 25°C)

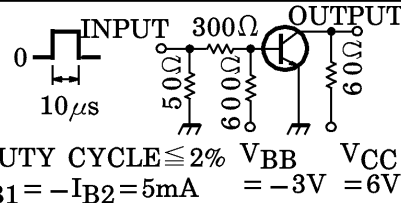
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	15	V
Collector-Emitter Voltage	V_{CEO}	12	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	400	mA
Base Current	I_B	50	mA
Collector Power Dissipation	P_C	100	mW
Junction Temperature	T_j	125	°C
Storage Temperature Range	T_{stg}	-55~125	°C



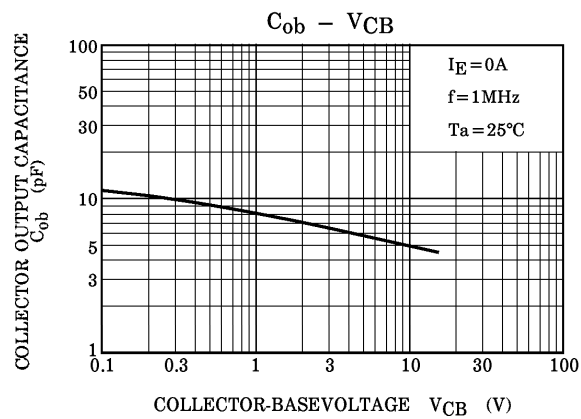
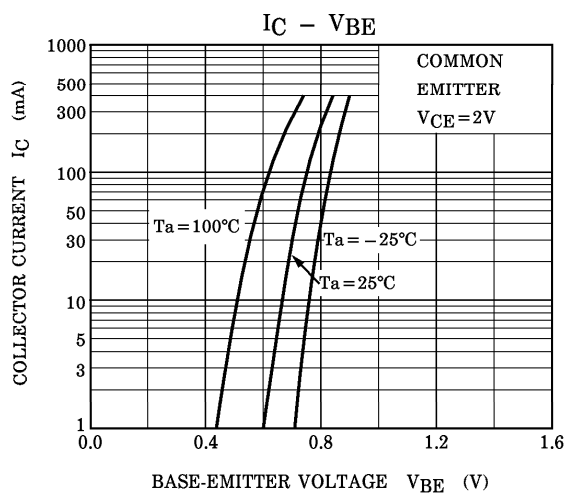
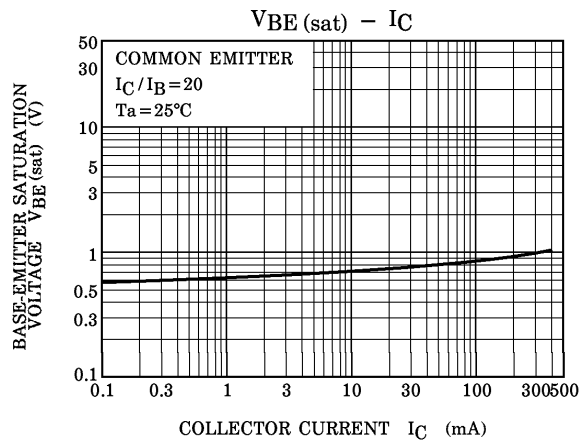
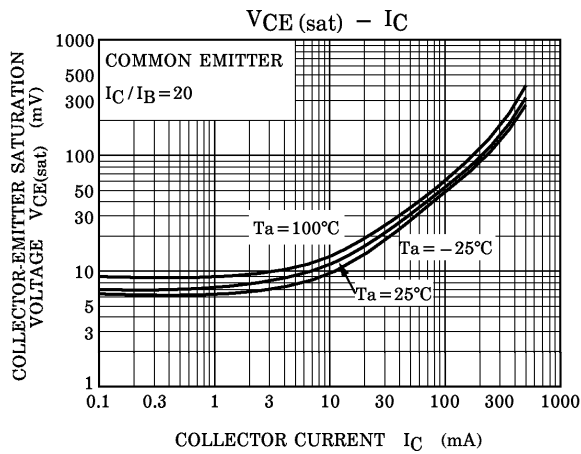
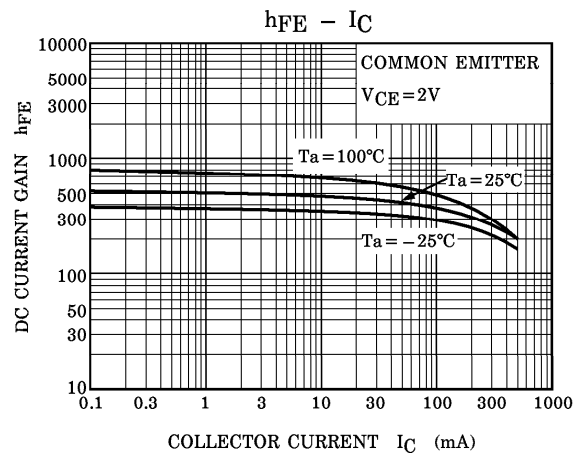
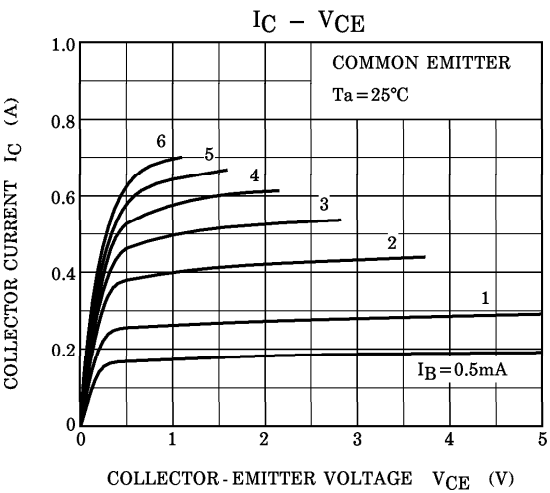
MARKING

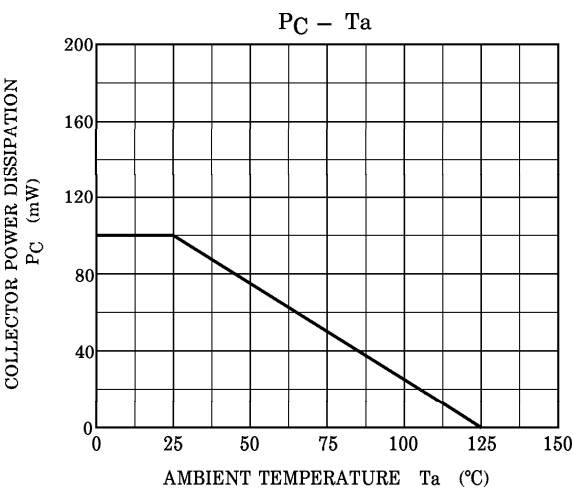


ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I _{CBO}	V _{CB} = 15V, I _E = 0	—	—	0.1	μA
Emitter Cut-off Current		I _{EBO}	V _{EB} = 5V, I _C = 0	—	—	0.1	μA
DC Current Gain		h _{FE} (Note)	V _{CE} = 2V, I _C = 10mA	300	—	1000	
Collector-Emitter Sturation Voltage	V _{CE (sat)} (1)	I _C = 10mA, I _B = 0.5mA	—	15	30	mV	
	V _{CE (sat)} (2)	I _C = 200mA, I _B = 10mA	—	110	250		
Base-Emitter Voltage		V _{BE (sat)}	I _C = 200mA, I _B = 10mA	—	0.87	1.2	V
Transition Frequency		f _T	V _{CE} = 2V, I _C = 10mA	80	130	—	MHz
Collector Output Capacitance		C _{ob}	V _{CB} = 10V, I _E = 0, f = 1MHz	—	4.2	—	pF
Collector-Emitter On Resistance		R _{on}	I _B = 1mA, V _{in} = 1V _{rms} , f = 1kHz	—	0.9	—	Ω
Switching Time	Turn-on Time	t _{on}	 DUTY CYCLE ≤ 2% I _{B1} = -I _{B2} = 5mA	—	85	—	ns
	Storage Time	t _{stg}		—	170	—	
	Fall Time	t _f		—	40	—	

(Note) h_{FE} Classification A : 300~600, B : 500~1000





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